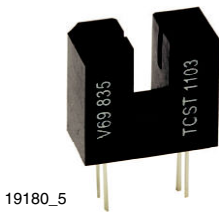
Transmissive Optical Sensor with Phototransistor Output



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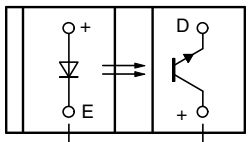

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FEATURES

- Package type: leaded
- Detector type: phototransistor
- Dimensions (L x W x H in mm): 11.9 x 6.3 x 10.8
- Gap (in mm): 3.1
- Typical output current under test: I_C = 4 mA (TCST1103)
- Typical output current under test: I_C = 2 mA (TCST1202)
- Typical output current under test: I_C = 0.5 mA (TCST1300)
- Daylight blocking filter
- Emitter wavelength: 950 nm
- Lead (Pb)-free soldering released
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb-free

e4

RoHS COMPLIANT

DESCRIPTION

The TCST1103, TCST1202, and TCST1300 are transmissive sensors that include an infrared emitter and phototransistor, located face-to-face on the optical axes in a leaded package which blocks visible light. These part numbers include options for aperture width.

APPLICATIONS

- Optical switch
- Photo interrupter
- Counter
- Encoder

PRODUCT SUMMARY

PART NUMBER	GAP WIDTH (mm)	APERTURE WIDTH (mm)	TYPICAL OUTPUT CURRENT UNDER TEST (1) (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED
TCST1103	3.1	1	4	Yes
TCST1202	3.1	0.5	2	Yes
TCST1300	3.1	0.25	0.5	Yes

Note

- Conditions like in table basic characteristics/coupler

ORDERING INFORMATION

ORDERING CODE	PACKAGING	VOLUME (1)	REMARKS
TCST1103	Tube	MOQ: 1020 pcs, 85 pcs/tube	Without mounting flange
TCST1202	Tube	MOQ: 1020 pcs, 85 pcs/tube	Without mounting flange
TCST1300	Tube	MOQ: 1020 pcs, 85 pcs/tube	Without mounting flange

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
COUPLER				
Total power dissipation	$T_{amb} \leq 25$ °C	P_{tot}	250	mW
Ambient temperature range		T_{amb}	- 55 to + 85	°C
Storage temperature range		T_{stg}	- 55 to + 100	°C
Soldering temperature	Distance to package: 2 mm; $t \leq 5$ s	T_{sd}	260	°C

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
INPUT (EMITTER)				
Reverse voltage		V_R	6	V
Forward current		I_F	60	mA
Forward surge current	$t_p \leq 10$ µs	I_{FSM}	3	A
Power dissipation	$T_{amb} \leq 25$ °C	P_V	100	mW
Junction temperature		T_j	100	°C
OUTPUT (DETECTOR)				
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V_{ECO}	7	V
Collector peak current	$t_p/T = 0.5$, $t_p \leq 10$ ms	I_{CM}	200	mA
Power dissipation	$T_{amb} \leq 25$ °C	P_V	150	mW
Junction temperature		T_j	100	°C

ABSOLUTE MAXIMUM RATINGS

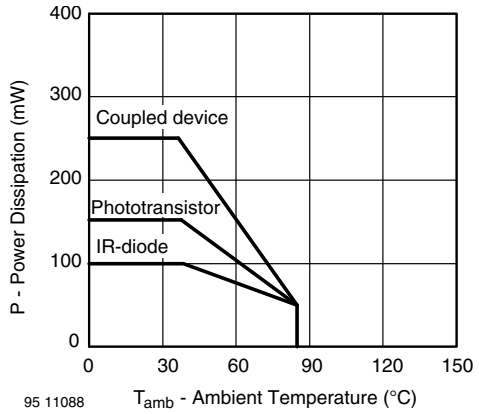

Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
COUPLER							
Current transfer ratio	V_{CE} = 5 V, I_F = 20 mA	TCST1103	CTR	10	20		%
		TCST1202	CTR	5	10		%
		TCST1300	CTR	1.25	2.5		%
Collector current	V_{CE} = 5 V, I_F = 20 mA	TCST1103	I_C	2	4		mA
		TCST1202	I_C	1	2		mA
		TCST1300	I_C	0.25	0.5		mA
Collector emitter saturation voltage	I_F = 20 mA, I_C = 1 mA	TCST1103	V_{CEsat}			0.4	V
	I_F = 20 mA, I_C = 0.5 mA	TCST1202	V_{CEsat}			0.4	V
	I_F = 20 mA, I_C = 0.1 mA	TCST1300	V_{CEsat}			0.4	V
Resolution, path of the shutter crossing the radiant sensitive zone	I_{Crel} = 10 % to 90 %	TCST1103	s		0.6		mm
		TCST1202	s		0.4		mm
		TCST1300	s		0.2		mm